

PSMN1R6-40YLC

N-channel 40 V 1.55 m Ω logic level MOSFET in LFPAK using NextPower technology

22 August 2012

Product data sheet

1. Product profile

1.1 General description

Logic level enhancement mode N-channel MOSFET in LFPAK package. This product is designed and qualified for use in a wide range of industrial, communications and domestic equipment.

1.2 Features and benefits

- High reliability Power SO8 package, qualified to 150°C
- Optimised for 4.5V Gate drive utilising NextPower Superjunction technology
- Ultra low QG, QGD, & QOSS for high system efficiencies at low and high loads
- Ultra low Rdson and low parasitic inductance

1.3 Applications

- DC-to-DC converters
- Load switching
- Power OR-ing
- Server power supplies
- Sync rectifier

1.4 Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V_{DS}	drain-source voltage	25 °C ≤ T _j ≤ 150 °C		-	-	40	V
I _D	drain current	T _{mb} = 25 °C; V _{GS} = 10 V; <u>Fig. 1</u>	[1]	-	-	100	Α
P _{tot}	total power dissipation	T _{mb} = 25 °C; <u>Fig. 2</u>		-	-	288	W
Tj	junction temperature			-55	-	150	°C
Static chara	cteristics	1	'	'	'		,
R _{DSon}	drain-source on-state resistance	$V_{GS} = 4.5 \text{ V}; I_D = 25 \text{ A}; T_j = 25 ^{\circ}\text{C};$ Fig. 12		-	1.45	1.8	mΩ
		V _{GS} = 10 V; I _D = 25 A; T _j = 25 °C; Fig. 12		-	1.25	1.55	mΩ
Dynamic cha	aracteristics						
Q_{GD}	gate-drain charge	V_{GS} = 4.5 V; I_D = 25 A; V_{DS} = 20 V; Fig. 14		-	15.3	-	nC



Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$Q_{G(tot)}$	total gate charge	V_{GS} = 4.5 V; I_D = 25 A; V_{DS} = 20 V; Fig. 14	-	59	-	nC

[1] Continuous current is limited by package.

2. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	S	source		D I
2	S	source		
3	S	source		G LIA
4	G	gate		mbb076 S
mb	D	mounting base; connected to drain	1 2 3 4	
			LFPAK; Power- SO8 (SOT1023)	

3. Ordering information

Table 3. Ordering information

	Table 6. Oracining in	omation						
Type number		Package	ge					
		Name	Description	Version				
	PSMN1R6-40YLC	LFPAK; Power-SO8	Plastic single-ended surface-mounted package (LFPAK); 4 leads	SOT1023				

4. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V_{DS}	drain-source voltage	25 °C ≤ T _j ≤ 150 °C		-	40	V
V_{DGR}	drain-gate voltage	25 °C ≤ T_j ≤ 150 °C; R_{GS} = 20 kΩ		-	40	V
V_{GS}	gate-source voltage			-20	20	V
I _D	drain current	V _{GS} = 10 V; T _{mb} = 25 °C; <u>Fig. 1</u>	[1]	-	100	Α
		V _{GS} = 10 V; T _{mb} = 100 °C; <u>Fig. 1</u>	[1]	-	100	Α
I _{DM}	peak drain current	pulsed; $t_p \le 10 \mu s$; $T_{mb} = 25 \text{ °C}$; Fig. 4		-	1304	Α
P _{tot}	total power dissipation	T _{mb} = 25 °C; <u>Fig. 2</u>		-	288	W
T _{stg}	storage temperature			-55	150	°C

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Symbol	Parameter	Conditions		Min	Max	Unit	
Tj	junction temperature			-55	150	°C	
$T_{sld(M)}$	peak soldering temperature			-	260	°C	
V _{ESD}	electrostatic discharge voltage	MM (JEDEC JESD22-A115)		1	-	kV	
Source-dra	in diode	1					
I _S	source current	T _{mb} = 25 °C	[1]	-	100	Α	
I _{SM}	peak source current	pulsed; $t_p \le 10 \mu s$; $T_{mb} = 25 ^{\circ}C$		-	1304	Α	
Avalanche ruggedness							
E _{DS(AL)S}	non-repetitive drain-source avalanche energy	V_{GS} = 10 V; $T_{j(init)}$ = 25 °C; I_D = 100 A; $V_{sup} \le$ 40 V; R_{GS} = 50 Ω; unclamped; Fig. 3		-	391	mJ	

[1] Continuous current is limited by package.

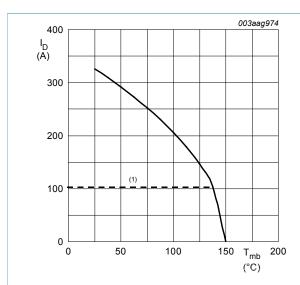


Fig. 1. Continuous drain current as a function of mounting base temperature

 $\label{eq:VGS} V_{\textit{GS}}\!\geq\!10\,V$ (1) Capped at 100 A due to package.

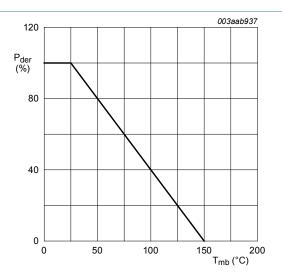


Fig. 2. Normalized total power dissipation as a function of solder point temperature

$$P_{der} = \frac{P_{tot}}{P_{tot(25^{\circ}C)}} \times 100\%$$

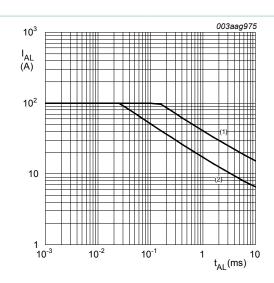


Fig. 3. Single pulse avalanche rating; avalanche current as a function of avalanche time

(1)
$$T_{j (init)} = 25$$
°C; (2) $T_{j (init)} = 100$ °C

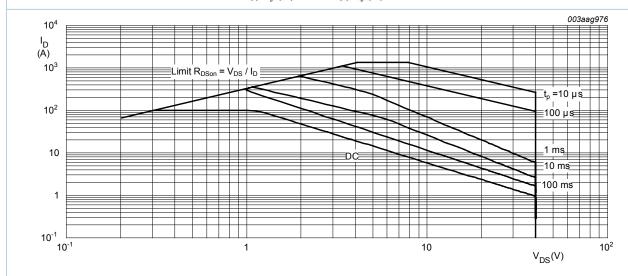


Fig. 4. Safe operating area; continuous and peak drain currents as a function of drain-source voltage

 $T_{mb} = 25^{\circ}C$; I_{DM} is a single pulse

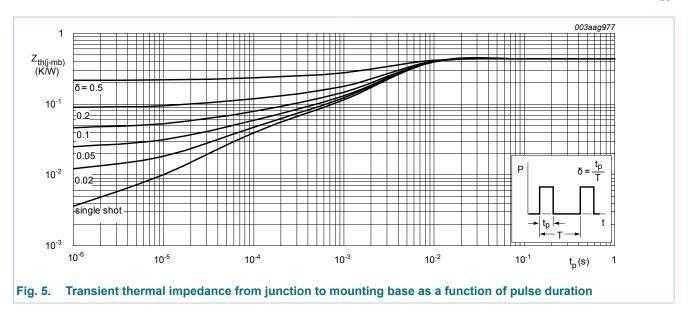
5. Thermal characteristics

Table 5. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R _{th(j-mb)}	thermal resistance from junction to mounting base	Fig. 5	-	0.35	0.43	K/W

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6. Characteristics

Table 6. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static chara	acteristics					
V _{(BR)DSS}	drain-source	$I_D = 250 \ \mu A; \ V_{GS} = 0 \ V; \ T_j = 25 \ ^{\circ}C$	40	-	-	V
	breakdown voltage	$I_D = 250 \ \mu A; \ V_{GS} = 0 \ V; \ T_j = -55 \ ^{\circ}C$	36	-	-	V
$V_{GS(th)}$	gate-source threshold voltage	I _D = 1 mA; V _{DS} = V _{GS} ; T _j = 25 °C; Fig. 10; Fig. 11	1.05	1.46	1.95	V
		I _D = 10 mA; V _{DS} = V _{GS} ; T _j = 150 °C	0.5	-	-	V
		$I_D = 1 \text{ mA}; V_{DS} = V_{GS}; T_j = -55 \text{ °C}$	-	-	2.25	V
I _{DSS}	drain leakage current	V _{DS} = 40 V; V _{GS} = 0 V; T _j = 25 °C	-	-	1	μΑ
		V _{DS} = 40 V; V _{GS} = 0 V; T _j = 150 °C	-	-	100	μΑ
I _{GSS}	gate leakage current	V _{GS} = 16 V; V _{DS} = 0 V; T _j = 25 °C	-	-	100	nA
		V_{GS} = -16 V; V_{DS} = 0 V; T_j = 25 °C	-	-	100	nA
R _{DSon}	drain-source on-state resistance	V_{GS} = 4.5 V; I_D = 25 A; T_j = 25 °C; Fig. 12	-	1.45	1.8	mΩ
		V_{GS} = 4.5 V; I_D = 25 A; T_j = 150 °C; Fig. 12; Fig. 13	-	-	3.2	mΩ
		V_{GS} = 10 V; I_D = 25 A; T_j = 25 °C; Fig. 12	-	1.25	1.55	mΩ
		V _{GS} = 10 V; I _D = 25 A; T _j = 150 °C; Fig. 12; Fig. 13	-	-	2.7	mΩ
R_G	gate resistance	f = 1 MHz	-	1.17	2.34	Ω

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Dynamic ch	naracteristics					
Q _{G(tot)}	total gate charge	I _D = 25 A; V _{DS} = 20 V; V _{GS} = 10 V; Fig. 14; Fig. 15	-	126	-	nC
		I _D = 25 A; V _{DS} = 20 V; V _{GS} = 4.5 V; Fig. 14	-	59	-	nC
		I _D = 0 A; V _{DS} = 0 V; V _{GS} = 10 V	-	115	-	nC
Q_{GS}	gate-source charge	I _D = 25 A; V _{DS} = 20 V; V _{GS} = 4.5 V;	-	17.7	-	nC
Q _{GS(th)}	pre-threshold gate- source charge	Fig. 14	-	12.5	-	nC
Q _{GS(th-pl)}	post-threshold gate- source charge		-	5.2	-	nC
Q_{GD}	gate-drain charge		-	15.3	-	nC
$V_{GS(pl)}$	gate-source plateau voltage	I _D = 25 A; V _{DS} = 20 V; <u>Fig. 14</u>	-	2.4	-	V
C _{iss}	input capacitance	V _{DS} = 20 V; V _{GS} = 0 V; f = 1 MHz;	-	7790	-	pF
C _{oss}	output capacitance	T _j = 25 °C; <u>Fig. 16</u>	-	1063	-	pF
C _{rss}	reverse transfer capacitance		-	409	-	pF
t _{d(on)}	turn-on delay time	V_{DS} = 20 V; R_L = 0.8 Ω ; V_{GS} = 4.5 V;	-	41	-	ns
t _r	rise time	$R_{G(ext)} = 4.7 \Omega$	-	48	-	ns
t _{d(off)}	turn-off delay time		-	86	-	ns
t _f	fall time		-	42	-	ns
Q _{oss}	output charge	$V_{GS} = 0 \text{ V}; V_{DS} = 20 \text{ V}; f = 1 \text{ MHz};$ $T_j = 25 \text{ °C}$	-	38.7	-	nC
Source-dra	in diode		'	'		,
V_{SD}	source-drain voltage	$I_S = 25 \text{ A}; V_{GS} = 0 \text{ V}; T_j = 25 ^{\circ}\text{C}; Fig. 17$	-	0.77	1.1	V
t _{rr}	reverse recovery time	I_S = 25 A; dI_S/dt = -100 A/ μ s; V_{GS} = 0 V; V_{DS} = 20 V; $Fig.~18$	-	44	-	ns
Q _r	recovered charge	I_S = 25 A; dI_S/dt = -100 A/ μ s; V_{GS} = 0 V; V_{DS} = 20 V	-	62	-	nC
t _a	reverse recovery rise time	$V_{GS} = 0 \text{ V}; I_S = 25 \text{ A}; dI_S/dt = -100 \text{ A/}\mu\text{s};$ $V_{DS} = 20 \text{ V}; Fig. 18$	-	26	-	ns
t _b	reverse recovery fall time		-	18	-	ns

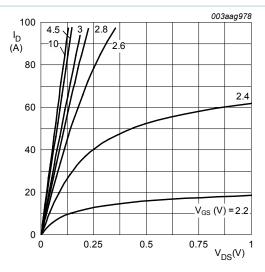


Fig. 6. Output characteristics; drain current as a function of drain-source voltage; typical values



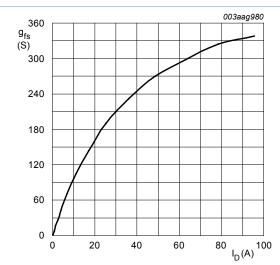


Fig. 8. Forward transconductance as a function of drain current; typical values

$$T_j = 25$$
°C; $V_{DS} = 10V$

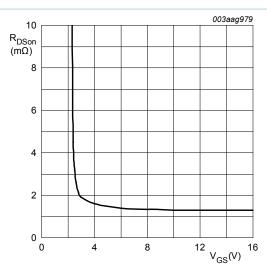


Fig. 7. Drain-source on-state resistance as a function of gate-source voltage; typical values

$$T_j = 25$$
°C; $I_D = 25$ A

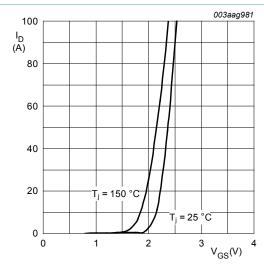


Fig. 9. Transfer characteristics; drain current as a function of gate-source voltage; typical values

$$V_{DS} = 10V$$

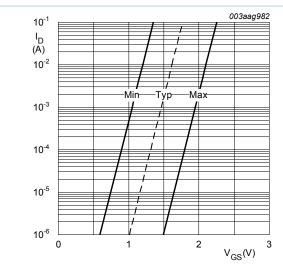


Fig. 10. Sub-threshold drain current as a function of gate-source voltage

$$T_j = 25^{\circ}C; \ V_{DS} = 5V$$

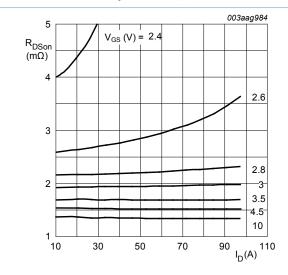


Fig. 12. Drain-source on-state resistance as a function of drain current; typical values

$$T_j = 25^{\circ}C$$

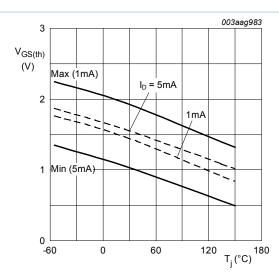


Fig. 11. Gate-source threshold voltage as a function of junction temperature

$$V_{DS} = V_{GS}$$

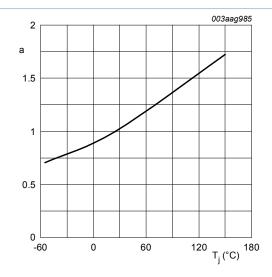


Fig. 13. Normalized drain-source on-state resistance factor as a function of junction temperature

$$a = \frac{R_{DSon}}{R_{DSon (25^{\circ}\text{C})}}; V_{GS} \leq \mathbf{10}V$$

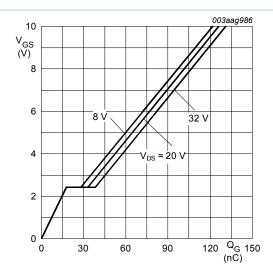
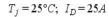


Fig. 14. Gate-source voltage as a function of gate charge; typical values



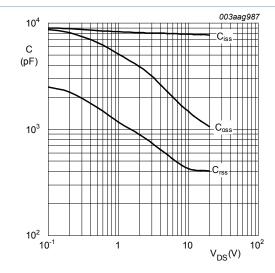


Fig. 16. Input, output and reverse transfer capacitances | Fig. 17. Source current as a function of source-drain as a function of drain-source voltage; typical values

$$V_{GS} = \mathbf{0}V; \ f = \mathbf{1}MHz$$

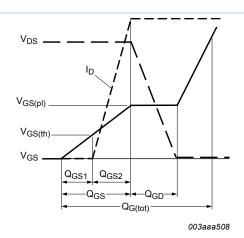
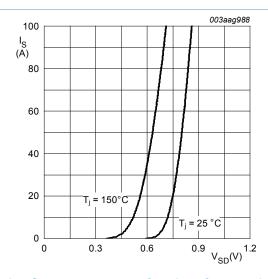
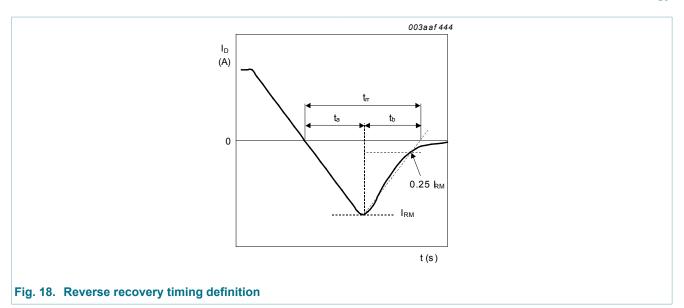


Fig. 15. Gate charge waveform definitions

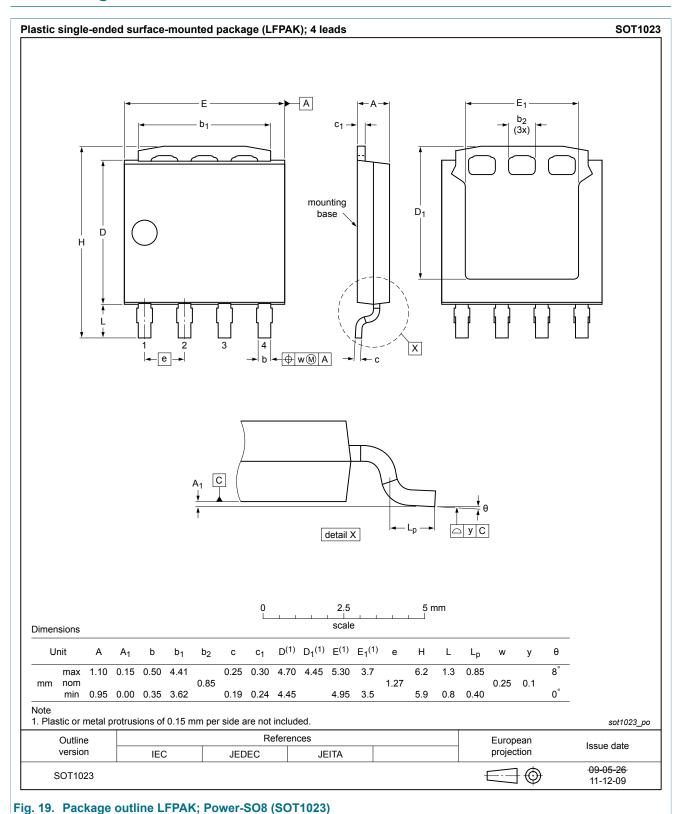


voltage; typical values

$$V_{GS} = 0V$$



7. Package outline



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8. Legal information

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